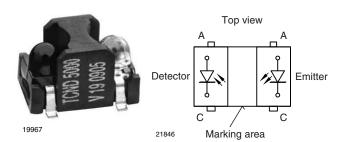


Vishay Semiconductors

Reflective Optical Sensor with PIN Photodiode Output

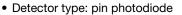


DESCRIPTION

The TCND5000 is a reflective sensor that includes an infrared emitter and pin photodiode in a surface mount package which blocks visible light.

FEATURES

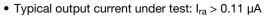
• Package type: surface mount





• Peak operating distance: 6 mm

 Operating range within > 20 % relative collector current: 2 mm to 25 mm



· Daylight blocking filter

· High linearity

• Emitter wavelength: 940 nm

• Lead (Pb)-free soldering released

• Moisture sensitivity level (MSL): 4

 Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

APPLICATIONS

- · Proximity sensor
- Object sensor
- Motion sensor
- Touch key

| PRODUCT SUMMARY | | | | |
|-----------------|--|--|--|---|
| PART NUMBER | DISTANCE FOR MAXIMUM CTR _{rel} (1) (mm) | DISTANCE RANGE FOR RELATIVE I _{out} > 20 % (mm) | TYPICAL OUTPUT CURRENT UNDER TEST (2) (mA) | DAYLIGHT BLOCKING FILTER INTEGRATED |
| TCND5000 | 6 | 2 to 25 | 0.15 | Yes |

Notes

 $^{(1)}$ CTR: current transfere ratio, I_{out}/I_{in}

(2) Conditions like in table basic charactristics/sensors

| ORDERING INFORMATION | | | | | | |
|----------------------|---------------|------------------------------|---------|--|--|--|
| ORDERING CODE | PACKAGING | VOLUME (1) | REMARKS | | | |
| TCND5000 | Tape and reel | MOQ: 2000 pcs, 2000 pcs/reel | Drypack | | | |

Note

(1) MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | |
|--|---|-----------------|-------|------|--|--|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | | | |
| INPUT (EMITTER) | | | | | | | |
| Reverse voltage | | V_{R} | 5 | V | | | |
| Forward current | | I _F | 100 | mA | | | |
| Peak forward current | $t_p = 50 \mu s$, $t = 2 ms$, $T_{amb} \le 25 ^{\circ}C$ | I _{FM} | 500 | mA | | | |
| Power dissipation | | P _V | 190 | mW | | | |
| Junction temperature | | Tj | 100 | °C | | | |



Vishay Semiconductors Reflective Optical Sensor with PIN Photodiode Output

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | |
|--|-------------------|------------------|---------------|------|--|--|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | | | |
| OUTPUT (DETECTOR) | OUTPUT (DETECTOR) | | | | | | |
| Reverse voltage | | V _R | 60 | V | | | |
| Power dissipation | | P _V | 75 | mW | | | |
| Junction temperature | | Tj | 100 | °C | | | |
| SENSOR | | | | | | | |
| Ambient temperature range | | T _{amb} | - 40 to + 85 | °C | | | |
| Storage temperature range | | T _{stg} | - 40 to + 100 | °C | | | |
| Soldering temperature | acc. fig. 14 | T _{sd} | 260 | °C | | | |

ABSOLUTE MAXIMUM RATINGS

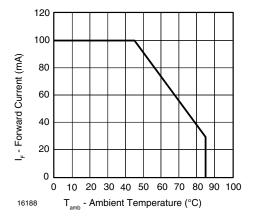


Fig. 1 - Forward Current Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|---|--|------------------|--------------------|-------|------|-------|
| PARAMETER | TEST CONDITION SYMBOL MIN. TYP. MA | | | | MAX. | UNIT |
| INPUT (EMITTER) (1) | | | | | | |
| Forward voltage | $I_F = 50 \text{ mA}, t_p = 20 \text{ ms}$ | V_{F} | | 1.2 | 1.5 | V |
| Temperature coefficient of V _F | I _F = 1 mA | TK _{VF} | | - 1.3 | | mV/K |
| Reverse current | V _R = 5 V | I _R | | | 10 | μA |
| Junction capacitance | $V_R = 0 V, f = 1 MHz, E = 0 Ix$ | C _j | | 25 | | pF |
| Radiant intensity | $I_F = 20 \text{ mA}, t_p = 20 \text{ ms}$ | l _e | | 7 | 75 | mW/sr |
| Angle of half intensity | | φ | ± 12 | | deg | |
| Peak wavelength | I _F = 100 mA | λ_{P} | 930 | 940 | | nm |
| Spectral bandwidth | I _F = 100 mA | Δλ | | 50 | | nm |
| Temperature coefficient of λ_p | I _F = 100 mA | TKλ _P | | 0.2 | | nm/K |
| Rise time | I _F = 100 mA | t _r | t _r 800 | | | ns |
| Fall time | I _F = 100 mA | t _f | | 800 | | ns |
| Virtual source diameter | Method: 63 % encircled energy | d | | 1.2 | | mm |



Reflective Optical Sensor with PIN Vishay Semiconductors Photodiode Output

| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | |
|---|--|--------------------|--------------------|------|------|-----|--|
| PARAMETER | TEST CONDITION SYMBOL MIN. | | TYP. | MAX. | UNIT | | |
| OUTPUT (DETECTOR) (2) | | | | | | | |
| Forward voltage | I _F = 50 mA | V _F | | 1 | 1.3 | V | |
| Breakdown voltage | I _R = 100 μA | V_{BR} | 60 | | | V | |
| Reverse dark current | V _R = 10 V, E = 0 lx | I _{ro} | | 1 | 10 | nA | |
| Diode capacitance | V _R = 5 V, f = 1 MHz, E = 0 lx | C _D | | 1.8 | | pF | |
| Reverse light current | $E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $V_R = 5 \text{ V}$ | I _{ra} | I _{ra} 12 | | | μА | |
| Temperature coefficient of I _{ra} | $\lambda = 870 \text{ nm}, V_R = 5 \text{ V}$ | TK _{ira} | | 0.2 | | %/K | |
| Angle of half intensity | | φ ± 15 | | | deg | | |
| Wavelength of peak sensitivity | | λ _P 930 | | | nm | | |
| Range of spectral bandwidth | pectral bandwidth λ _{0.5} 840 to 1050 | | | nm | | | |
| SENSOR | | | | | | | |
| Reverse Light Current | V _R = 2.5 V, I _F = 20 mA, D = 30 mm, reflective mode: see figure 2 | I _{ra} | 110 | | | nA | |

Note

- (1) See figures 2 to 8 accordingly
- (2) See figures 9 to 12 accordingly

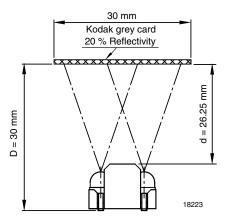


Fig. 2 - Test Circuit

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

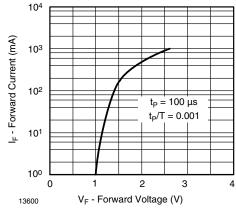


Fig. 3 - Forward Current vs. Forward Voltage

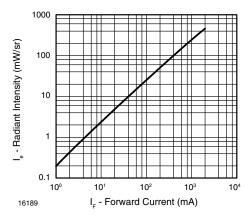


Fig. 4 - Radiant Intensity vs. Forward Current

Vishay Semiconductors Reflective

VISHAY.

tors Reflective Optical Sensor with PIN Photodiode Output

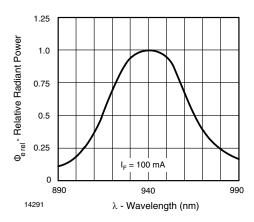


Fig. 5 - Relative Radiant Power vs. Wavelength

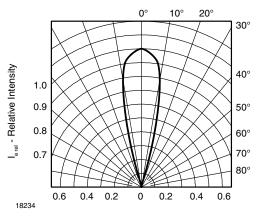


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

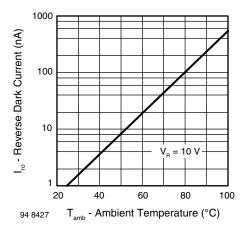


Fig. 7 - Reverse Dark Current vs. Ambient Temperature

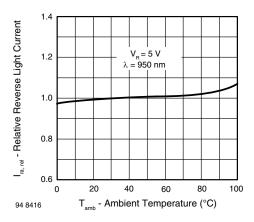


Fig. 8 - Relative Reverse Light Current vs. Ambient Temperature

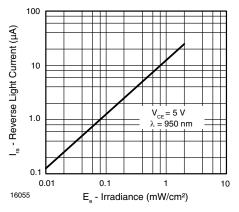


Fig. 9 - Reverse Light Current vs. Irradiance

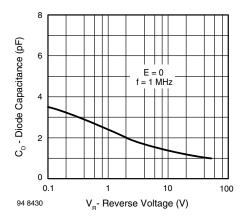


Fig. 10 - Diode Capacitance vs. Reverse Voltage



Reflective Optical Sensor with PIN Vishay Semiconductors Photodiode Output

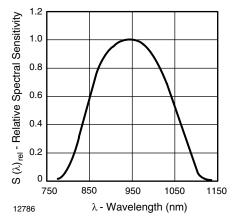


Fig. 11 - Relative Spectral Sensitivity vs. Wavelength

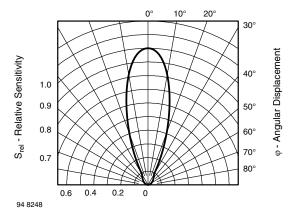


Fig. 12 - Relative Radiant Sensitivity vs. Angular Displacement

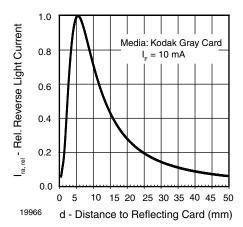
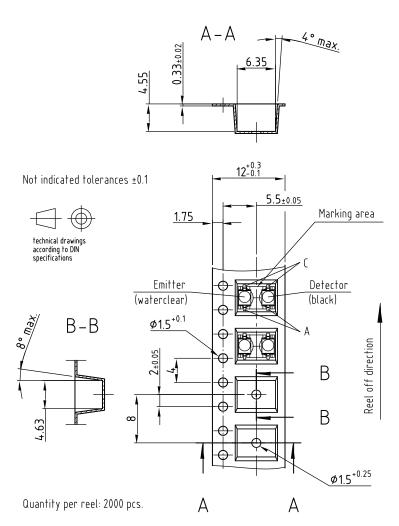


Fig. 13 - Relative Reverse Light Current vs. Distance

Vishay Semiconductors Reflective Optical Sensor with PIN Photodiode Output



TAPING Dimensions in millimeters



Material of Blistertape: PC black Sealing of cavities with hot sealing cover tape, C-Pak Type CP - 2010 AS (Thickness: 0.055 - 0.075mm; Base Material: Polyester)

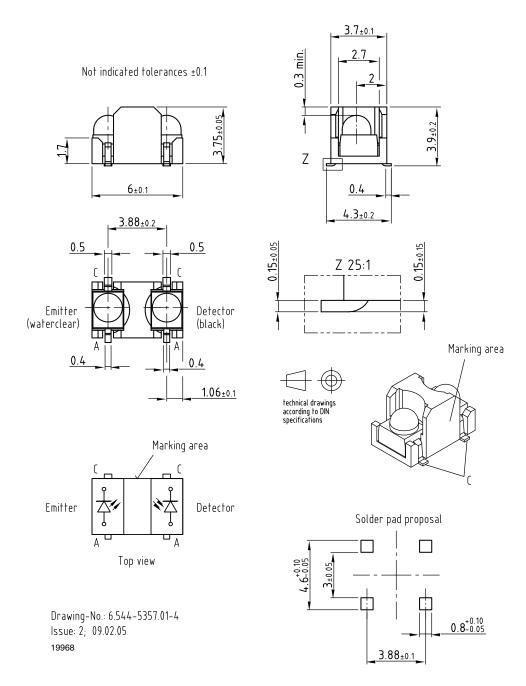
Drawing-No.: 9.700-5281.01-4 Issue: 4; 10.02.05

18222



Reflective Optical Sensor with PIN Vishay Semiconductors Photodiode Output

PACKAGE DIMENSIONS in millimeters



Vishay Semiconductors Reflective Optical Sensor with PIN Photodiode Output



PRECAUTIONS FOR USE

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

2. Storage

- 2.1 Storage temperature and rel. humidity conditions are: 5 $^{\circ}\text{C}$ to 30 $^{\circ}\text{C}$, RH 60 %
- 2.2 Floor life must not exceed 72 h, acc. to JEDEC level 4, J-STD-020.

Once the package is opened, the products should be used within 72 h. Otherwise, they should be kept in a damp proof box with desiccant.

Considering tape life, we suggest to use products within one year from production date.

- 2.3 If opened more than 72 h in an atmosphere 5 °C to 30 °C, RH 60 %, devices should be treated at 60 °C \pm 5 °C for 15 h.
- 2.4 If humidity indicator in the package shows pink color (normal blue), then devices should be treated with the same conditions as 2.3

REFLOW SOLDER PROFILES

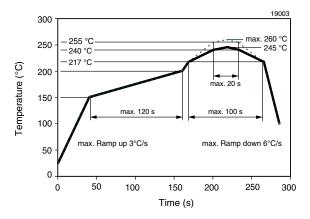


Fig. 14 - Lead (Pb)-Free Reflow Solder Profile

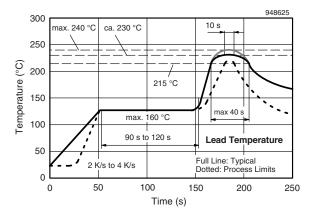


Fig. 15 - Lead Tin (SnPb) Reflow Solder Profile



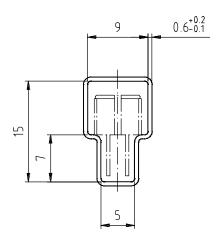
Vishay Semiconductors

Packaging and Ordering Information

| PART NUMBER | MOQ (1) | PCS PER TUBE | TUBE SPEC. (FIGURE) | CONSTITUENTS (FORMS) |
|---------------|---------|--------------|------------------------|-------------------------|
| CNY70 | 4000 | 80 | 1 | 28 |
| TCPT1300X01 | 2000 | Reel | (2) | 29 |
| TCRT1000 | 1000 | Bulk | - | 26 |
| TCRT1010 | 1000 | Bulk | - | 26 |
| TCRT5000 | 4500 | 50 | 2 | 27 |
| TCRT5000L | 2400 | 48 | 3 | 27 |
| TCST1030 | 5200 | 65 | 5 | 24 |
| TCST1030L | 2600 | 65 | 6 | 24 |
| TCST1103 | 1020 | 85 | 4 | 24 |
| TCST1202 | 1020 | 85 | 4 | 24 |
| TCST1230 | 4800 | 60 | 7 | 24 |
| TCST1300 | 1020 | 85 | 4 | 24 |
| TCST2103 | 1020 | 85 | 4 | 24 |
| TCST2202 | 1020 | 85 | 4 | 24 |
| TCST2300 | 1020 | 85 | 4 | 24 |
| TCST5250 | 4860 | 30 | 8 | 24 |
| TCUT1300X01 | 2000 | Reel | (2) | 29 |
| TCZT8020-PAER | 2500 | Bulk | - | 22 |

Notes

TUBE SPECIFICATION FIGURES



With rubber stopper Tolerance: ±0.5mm Length: 575±1mm

Drawing-No.: 9.700-5097.01-4

Issue: 1; 25.02.00

15198

Fig. 1

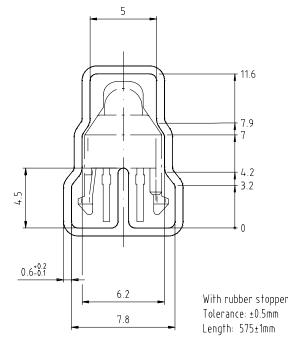
⁽¹⁾ MOQ: minimum order quantity

⁽²⁾ Please refer to datasheets

Packaging and Ordering Information

Vishay Semiconductors Packaging and Ordering Information



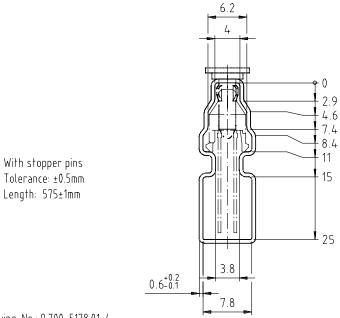


Drawing-No.: 9.700-5139.01-4 Issue: 1; 10.05.00

Drawing refers to following types: TCRT 5000

15210

Fig. 2



Drawing-No.: 9.700-5178.01-4 Issue: 1; 25.02.00

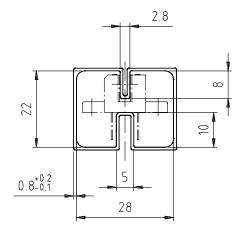
15201

Fig. 3





Packaging and Ordering Information Vishay Semiconductors



With rubber stopper Tolerance: ±0.5mm Length: 575±1mm

Drawing-No.: 9.700-5100.01-4

Issue: 1; 25.02.00

15199

15202

Fig. 4

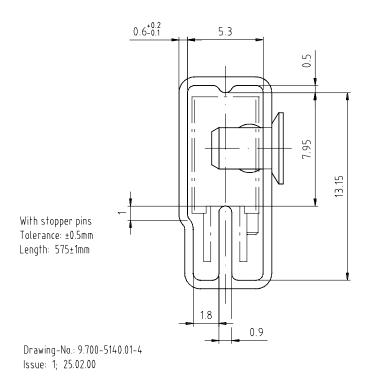
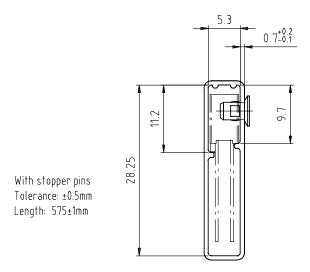


Fig. 5

Packaging and Ordering Information

Vishay Semiconductors Packaging and Ordering Information



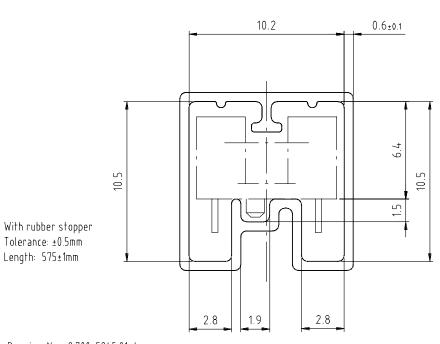


Drawing-No.: 9.700-5205.01-4

Issue: 1; 25.02.00

15196

Fig. 6



Drawing-No.: 9.700-5245.01-4

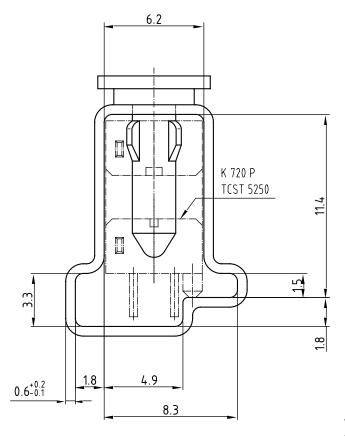
Issue: 1; 25.02.00 15195

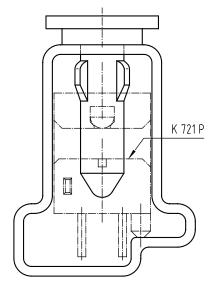
Fig. 7





Packaging and Ordering Information Vishay Semiconductors





Drawing-No.: 9.700-5222.01-4

Issue: 2; 19.11.04

20257

With stopper pins Tolerance: ±0.5mm Length: 450±1mm All dimensions in mm

Fig. 8



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Vishay

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